

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S235	5	(silicon\$1on\$1sapphire) near15 (gan or gallium near2 nitride)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/02 10:10
S234	789	(silicon near2 sapphire or silicon\$1on\$1sapphire) near15 (gan or gallium near2 nitride)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/02 10:10
L1	11597	convex near15 substrate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/13 10:35
L2	1	convex near15 substrate near15 (sapphire) near10 (silicon)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/13 10:36
L4	0	convex near15 substrate near15 sos!	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/13 10:40
L3	1721	convex near15 substrate near15 sos	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/13 10:40
S140	54	(sos! or "silicon-on-sapphire") same (gan or gallium near2 nitride)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/13 10:41
S67	113	(sapphire or "al.sub.2o.sub.3") near2 substrate and ("iii-v") and both near2 side	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/13 10:41
L8	107	(sos! or "silicon-on-sapphire") same (gan or gallium near2 nitride)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/13 10:41

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L7	126	(sapphire or "al.sub.2o.sub.3") near2 substrate near15 silicon and ("iii-v") near15 epitax\$5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/13 10:41
L6	570	(sapphire or "al.sub.2o.sub.3") near2 substrate near15 silicon and ("iii-v")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/13 10:41
L5	2105	(sapphire or "al.sub.2o.sub.3") near2 substrate and ("iii-v")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/13 10:41
S23 3	20	ueda near2 tetsuzo.in. and (bow\$5 or warp\$4)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/13 10:42
S22 8	2	warp\$5 near15 (si or silicon) near10 (sapphire or "al.sub.2o.sub.3") near10 (back or backside)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/13 10:42
S22 3	121	((sapphire near silicon) or ("sapphire-on-silicon")) same (gan or gallium near2 nitride or "iii-v") and @py<"2002"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/13 10:42
S17 9	52	(silicon adj "on" adj sapphire or sos! or sapphire adj "on" adj silicon) near10 substrate same (gan or gallium near2 nitride)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/13 10:42
L11	121	((sapphire near silicon) or ("sapphire-on-silicon")) same (gan or gallium near2 nitride or "iii-v") and @py<"2002"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/13 10:42
L10	3	warp\$5 near15 (si or silicon) near10 (sapphire or "al.sub.2o.sub.3") near10 (back or backside)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/13 10:42
L9	24	ueda near2 tetsuzo.in. and (bow\$5 or warp\$4)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/13 10:42

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L13	8	(silicon adj "on" adj sapphire or sos! or sapphire adj "on" adj silicon) near10 (bow\$4 or warp\$5 or convex)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/13 10:43
L12	89	(silicon adj "on" adj sapphire or sos! or sapphire adj "on" adj silicon) near10 substrate same (gan or gallium near2 nitride)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/11/13 10:43